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SERIAL NUMB 10/717,149				GROUP ART UNIT 2818		ATTORNEY DOCKET NO. ATM-262				
APPLICANTS										
Alan L. Renninger, Cupertino, CA;										
James J., Shen, Colorado Springs, CO;										
** CONTINUING DATA **********************************										
** FOREIGN APPLICATIONS ************************************										
IF REQUIRED, FOREIGN FILING LICENSE GRANTED ** 02/17/2004										
Foreign Priority claimed 35 USC 119 (a-d) conditions met Verified and Acknowledged Examiner's Signature Initials				STATE OR	SHEETS T		тот	AL	INDEPENDENT	
				COUNTRY CA	DRAWING 3		CLAII 24		CLAIMS 4	
ADDRESS 003897 SCHNECK & SC P.O. BOX 2-E SAN JOSE , CA 95109-0005								- "	·	
TITLE Wether Embedded EEPF	od (of Forming a colland mothod of form	Low ing the s	r voltage same tunn	e ga	ti c Oxio	xide le l	.la avje	yer and er in an	
	EEPROM Cell.						☐ All Fees			
	FEES: Authority has been given in Paper No to charge/credit DEPOSIT ACCOUNT No for following:					1.16 Fees (Filing) 1.17 Fees (Processing Ext. of time) 1.18 Fees (Issue)				

In the Title:

Please replace the title with:

METHOD OF FORMING A LOW VOLTAGE GATE OXIDE LAYER AND TUNNEL OXIDE LAYER IN AN EEPROM CELL